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Fabrication of SnO-SnO₂ nanocomposites with p-n heterojunctions for low-temperature sensing of NO₂ gas

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In this report, the fabrication of novel SnO₂-SnO nanostructure with p-n heterojunction is achieved through a facile one-pot and low-cost hydrothermal process. The structure and properties of the nanocomposites were analyzed with X-ray techniques and electron microscopy. The HRTEM characterizations showed that p-n heterojunction was formed with small n-type SnO₂ nanocrystals dispersed on the surface of large p-type SnO crystals. Compared to the single SnO₂-based material, the gas sensor fabricated from SnO₂-SnO composite exhibited enhanced sensing performance for NO₂ gas detection with a limit of detection and sensitivity of 0.1 ppm and 0.26 ppm, respectively, at relative low operation temperature (50 °C). Moreover, the p-n heterojunction exhibited high sensing selectivity for NO₂. Such high sensing sensitivity and low operation temperature make the SnO₂-SnO p-n nanomaterial promising gas sensor for practical NO₂ gas detection. The improved sensing response characteristics of the hybrid material could be attributed to the p-n junctions formed through the in situ growth of SnO₂ nanocrystals on SnO nanoplates. The present study is helpful for the design of novel gas sensing materials and the development of NO₂ gas sensors.

1. Introduction

Tin dioxide (SnO₂) nanomaterials have been widely applied in the field of gas sensing for decades due to its unique sensing properties, such as high sensitivity, fast response and high stability etc. Tin dioxide is a typical n-type semiconductor material with rutile crystalline structure and wide band gap (3.6 eV). Many endeavors have been devoted to the design of SnO₂ nanostructures and have received many excellent achievements. Especially, owing to its excellent tunable physicochemical properties and the size-, shape- and exposed surface-dependent gas sensing properties, SnO₂ nanomaterials with various structures have been designed for gas sensing, such as zero-dimensional (0D) particles or clusters, one-dimensional (1D) nanofibers or nanorods, two-dimensional (2D) nanosheets and three-dimensional (3D) hierarchical and porous hollow structures, etc. In order to overcome the intrinsic shortcomings of pure SnO₂ nanomaterials and to improve the sensing performance, large amount of SnO₂ nanomaterials doped with different dopants have been proposed recently. Among the doped materials, the semiconductor materials doped or loaded with noble metals such as Pt, Pd, Au, Ag, have been synthesized and the doped SnO₂ materials exhibited enhanced sensing performance. However, due to the high cost and the easy poisoning of noble metals by toxic gases, the application of noble metal-doped SnO₂ nanomaterials in gas sensors are largely limited. In recent years, it was found that hybrid sensing materials fabricated from different types of semiconductors by forming p-n heterojunction with SnO₂ nanomaterials can effectively increase charge transfer and enhance the sensing properties.

The unique heterojunction structure fabricated from SnO₂ and other doped or supported metal oxide materials with various morphologies exhibited outstanding gas sensing properties. Compared with gas sensors based on single SnO₂ material, the nano-gas-sensors fabricated from p-n heterojunction structure of SnO₂/metal oxides can largely overcome the shortcomings of high resistance, high working temperature and long response time, etc. In a p-n junction structure, between the contact sections of n- and p-type semiconductor materials, the conduction and valence bands usually bend and the Femi levels are equalized associated with the formation of depletion layers, which directly results in the improvement of the conductivity and the acceleration of response and recovery times. Moreover, the morphologies of metal oxides with hierarchical structures can be tuned to enhance gas diffusion rate and enlarge the specific surface area, and thus to further improve the gas sensing properties. In recent years, the typical SnO₂-based nanomaterials with p-n heterojunction have been designed as gas sensors, for example SnO₂ nanospheres, SnO₂ nanowires, SnO₂ nanofibers, SnO₂ nanorods, SnO₂ nanosheets, CuO nanoparticles and ZnO/SnO₂ nanocomposites with p-Mn heterojunctions for acetone sensing, etc.
core-shell structural microspheres for ethanol sensing and so on. Meanwhile, the heterostructures of SnO$_2$ metal oxides materials are not only confined in gas sensing application, but also applied to electrochemical sensing, photocatalysts, lithium ion battery, dye-sensitized solar cells, etc.

Nitrogen dioxide (NO$_2$) is a kind of reddish brown, high activity gaseous substance, which is mainly released from high-temperature combustion processes, such as the emissions of exhaust gas of automobiles, exhaust gas discharged from power station and so on. It is deserved to mention that NO$_2$ is also a key composition of acid rain which will cause a variety of environmental effects, including the visibility reduction of atmosphere, surface water acidification and increased harmful toxins in fish and other aquatic organisms in water. Therefore, efficient sensing materials for sensitive detection of NO$_2$ gas in the ambient with fast response are essentially required. In this paper, to develop practically useful NO$_2$ sensing materials, SnO-SnO$_2$ nanocomposites and single SnO$_2$ nanoparticles were prepared by the same synthetic method and treatment procedure. In a typical synthesis, 0.105 g of SnCl$_2$·2H$_2$O (Beijing Chemical Reagent Co., Ltd., China, AR, 98%) and 0.054 g of urea were dissolved in 15 mL deionized water under magnetic stirring. Notably, this mixed solution was transferred to a 25 mL Teflon-lined stainless steel vessel and the hydrothermal process was performed at 180 °C for several hours in air. The material and treatment procedure. In a typical synthesis, 0.105 g of SnCl$_2$·5H$_2$O (Chengdu Gracia Chemical Technology Co., Ltd., China, AR, 99%), 0.054 g of urea were dispersed in 15 mL deionized water under magnetic stirring. Notably, this mixed solution is colorless and clear, which is different from that of SnCl$_2$·2H$_2$O. The following hydrothermal and purification processes are same with the aforementioned.

2. Experimental Section

2.1 Material preparation

All reagents are analytical grade and were used without further purification unless that was specified. The SnO-SnO$_2$ nanocomposites were synthesized by a hydrothermal process. Typically, 0.066 g of SnCl$_2$·2H$_2$O (Beijing Chemical Reagent Co., Ltd., China, AR, 98%) and 0.054 g of urea were dispersed in 15 mL deionized water under moderate stirring for about 30 min until the mixture appear homogeneous milky solution. Then, the mixed solution was transferred to a 25 mL Teflon-lined stainless steel vessel and the hydrothermal process was performed at 180 °C for 16 h. The formed SnO$_2$-SnO composites were washed with water and ethanol by centrifugation (3000 rpm), and then dried at 40 °C for several hours in air to obtain the final product. In order to compare the gas sensing performances of the prepared SnO$_2$-SnO$_2$ nanocomposites and single SnO$_2$ material, SnO$_2$ nanoparticles were also prepared by the same synthetic method and treatment procedure. In a typical synthesis, 0.105 g of SnCl$_2$·5H$_2$O (Chengdu Gracia Chemical Technology Co., Ltd., China, AR, 99%), 0.054 g of urea were dispersed in 15 mL deionized water under magnetic stirring. Notably, this mixed solution is colorless and clear, which is different from that of SnCl$_2$·2H$_2$O. The following hydrothermal and purification processes are same with the aforementioned.

2.2 Material characterization

The gas sensing behaviors of the samples were tested on a heating ceramic plate of the CGS-1TP instrument by pressing sample firmly with two probes. The products were firstly mixed with N, N-dimethylformamide (DMF) to form homogeneous suspensions which were then drip-dropped on commercial ceramic substrates with Ag-Pd interdigitated electrodes. The as-prepared samples were dried at 55 °C during the process of dripping in air. The gas sensing measurements were conducted with the prepared sensors at different operation temperatures with a fixed working voltage of 9 V. The operation temperature was changed by external temperature controller under heating ceramic plate and that could be adjusted from room temperature to 500 °C with the rate of 3-5 °C/s (relative humidity is about 38%). The sensor was preheated for about 30 min at certain target temperature until the resistance of the materials reached a stable range, and then was sealed in an 18 L test chamber. The target gas was injected into the test chamber through the injection pore. During the measurements, the fans for gas mixing were turned on till the resistance of material reaches a stable range. After gas sensing tests, the test chamber was opened to make the sensor expose to the fresh air and the fans were turned off. These procedures were repeated for the gas sensing tests at different conditions. Here, the response of the sensor is defined as $R/R_\infty$, where $R_\infty$ and $R$ are the resistances of sensor in target gas and air, respectively. The concentration of target gas could be calculated by equation 1.

$$Q = V \times C \times 10^{-6} \times \frac{273 + T_B}{273 + T}$$. Where $Q$ is the volume of target gas, $V$ is the volume of test chamber, $C$ is the concentration of target gas, $T_B$ is the operation temperature and $T$ is the room temperature.

3. Results and Discussion

3.1 Synthesis and characterization of the gas sensing materials

In this study, two kinds of NO$_2$ gas sensing materials (SnO$_2$-SnO$_2$ nanocomposites and single SnO$_2$ nanoparticles) were prepared by.
one-pot hydrothermal processes. In the hydrothermal process, urea plays a key role for the formation of SnO$_2$-SnO composite. When temperature is higher than 90 °C, urea begins to hydrolyze and NH$_4^+$ and CO$_3^{2-}$ will be slowly released. With temperature further increasing, CO$_2$ and OH$^-$ can be produced from CO$_3^{2-}$ and NH$_4^+$, respectively. Owing to the limited oxygen in the solution, only a small part of SnO can be converted to SnO$_2$ to form the SnO$_2$-SnO composite. While the totally oxygen-free condition is hard to achieve in the hydrothermal process, pure SnO product can not be prepared with the present method. The main reactions from Sn$^{2+}$ and Sn$^{4+}$ precursors could be described as follows.

I. H$_2$NCONH$_2$ + 3H$_2$O $\rightarrow$ 2NH$_4^+$ + CO$_3^{2-}$ + OH$^-$ + H$^+$ (2)
II. Sn$^{2+}$ + 2OH$^-$ $\rightarrow$ Sn(OH)$_2$ (3)
Sn(OH)$_2$ $\rightarrow$ SnO + H$_2$O (4)
2SnO + O$_2$ $\rightarrow$ 2SnO$_2$ (5)
III. Sn$^{4+}$ + 4OH$^-$ $\rightarrow$ Sn(OH)$_4$ (6)
Sn(OH)$_4$ $\rightarrow$ SnO$_2$ + 2H$_2$O (7)

The composition and crystalline structure of the obtained products were first characterized by X-ray techniques and electron microscopy. As shown in Fig. 1A, the XRD pattern of the heterojunction structured SnO$_2$-SnO composites agrees well with the standard cassiterite (SnO$_2$, JCPDS card no.41-1445) and romarchite (SnO$_2$, JCPDS card no.06-0395). However, the product synthesized from SnCl$_2$·5H$_2$O shows only cassiterite SnO$_2$ phase (JCPDS card no.41-1445). It is noteworthy that compared with the diffraction peaks of the pure SnO$_2$ sample, the intensity and full widths at half maximum (FWHM) of the diffraction peaks from the SnO$_2$-SnO composites are much stronger and narrower. These results imply that the SnO$_2$ nanocrystals formed in the relatively larger crystal size than the pure SnO$_2$ sample. On the other hand, such results suggest that during the formation of SnO$_2$-SnO hybrid materials, the nucleation and crystal growth can be promoted. Interestingly, in the XRD pattern of the SnO$_2$-SnO, the intensity and FWHM of diffraction peaks from SnO$_2$ are much stronger and narrower than those from the SnO$_2$ component, suggesting that the SnO nanocrystals are much larger than SnO$_2$-SnO nanoparticles. Meanwhile, from the standard XRD data of SnO (JCPDS card no.06-0395), the diffraction peak of (101) has the highest intensity ($I_{(101)}/I_{(100)} = 0.11$), but the peak ratio of (001) and (101) is much increased with the much increased $I_{(001)}/I_{(101)}, I_{(002)}/I_{(101)}$ ratios of 1.1 and 1.26. Such XRD features strongly suggest that the formed SnO nanocrystals in SnO$_2$-SnO are predominated by exposed (001) facet. The lattice parameters of the (001), (101) and (002) facets were calculated to be $c = 0.485$, 0.485 and 0.436 nm, respectively, based on the MDI Jade 5.0 software. The crystallite sizes of SnO, SnO$_2$ in the SnO$_2$-SnO composite, and of the pure SnO$_2$ nanoparticles were evaluated to be 80.64, 28.4 and 4 nm, respectively, by the Scherrer equation: $d = 0.9 / B_{2θ} \cosθ$ ($λ$: wavelength of the X-ray; $θ$: angle of the peak; $B_{2θ}$: the peak width at half height) with the values of FWHM of the major

Fig. 1 (A) Typical XRD patterns of SnO$_2$-SnO nanocomposite and SnO$_2$ nanoparticles. For comparison, XRD data of bulk SnO (green bars) and SnO$_2$ (blue bars) from the Joint Committee Powder Diffraction Standard are also included. High resolution XPS spectra of Sn 3d$_{5/2}$ (B) and O 1s (C) of the SnO$_2$-SnO nanocomposite.
diffraction peaks of SnO (002) plane and SnO₂ (110) planes. The calculated crystalline sizes are in accordance with the following results from TEM and HRTEM measurements.

![Graph](image)

**Fig. 3** N₂ adsorption–desorption isotherms of the SnO₂–SnO composite (A) and pure SnO₂ nanoparticles (B). Insets are the corresponding pore size distributions.

The XPS spectral measurements were also carried out to identify the chemical states of the SnO₂–SnO composite. Fig. S1 shows the full scale survey spectrum of the sample. Clearly, the peaks from Sn, O, and C can be observed without the presence of any other impurities. From the high-resolution Sn 3d₈/₂ spectrum of the SnO₂–SnO composite shown in Fig. 1B, the two fitted peaks at 485.8 and 486.5 eV correspond to the Sn⁷⁺ and Sn⁴⁺ states, respectively. Fig. 1C shows the high-resolution O1s spectrum of the hybrid, in which the deconvoluted two peaks at binding energies of 529.9 and 531.2 eV correspond to the SnO₂ (Sn–O–Sn) and the oxygen of SnO (Sn=O), respectively. The XPS results agree well with that of the XRD measurements. Both XRD and XPS characterizations indicate that SnO₂–SnO₅ nanocrystallites have been successfully fabricated through the hydrothermal process.

Fig. 2A and B shows the TEM images of the as-prepared pure SnO₂ nanoparticles at different magnifications. It can be seen that the obtained SnO₂ nanoparticles have tiny size. Due to the absence of any surfactants and supporting materials, the produced SnO₂ nanoparticles exhibit aggregates with porous structure. Meanwhile, the SnO₂–SnO hybrids obtained by using different tin precursors through the same hydrothermal process exhibit much different morphology from that of pure SnO₂ material. Fig. 2C and D shows the TEM images of the SnO₂–SnO composite at different magnifications. It can be seen that in the composite, the SnO crystal exhibits laminal structure with several hundreds and tens nanometer in lateral size and thickness, respectively. At the same time, one layer of SnO₂ nanoparticles with approximately 4–10 nm in diameter are dispersed on the surface of the large SnO plates, forming the heterojunction structures. To further examine the p–n heterojunction structure, a typical HRTEM image of the SnO₂–SnO hybrid is shown in Fig. 2E. Highly crystalline SnO₂ nanocrystals with clear lattice fringes from different facets can be observed. Meanwhile, the lattice fringes corresponding to the (001) plane of SnO nanoplate can also be seen. The selected-area electron diffraction (SAED) pattern is shown in Fig. 2F. It can be seen that in addition to the diffraction cycles from multiple SnO₂ nanocrystals, there are also apparent diffraction spots, indicating the single crystalline phase of the SnO nanoplates. These electron microscopy analyses are in accordance with the above XRD and XPS measurements, showing the formation of SnO₂–SnO p–n structure with large SnO laminal crystals covered by small SnO₂ nanoparticles.

In order to quantitatively determine and compare the specific surface areas and pore volumes of the SnO₂ and SnO₂–SnO hybrids, multipoint BET surface area and pore volume measurements were carried out based on the nitrogen adsorption–desorption isotherms. The N₂ physisorption isotherms of the two samples and their corresponding Barret–Joyner–Halenda (BJH) pore size distribution curves are shown in Fig. 3. One can see that the SnO₂–SnO hybrids exhibit the isotherm feature of the H3 type according to the IUPAC classification, whereas the pure SnO₂ sample shows a H2 type. From the measurements, the BET surface areas of SnO₂–SnO and SnO₂ are 45.6 and 178.9 m²/g, respectively. As described above, the high surface area of the pure SnO₂ nanocrystals could be attributed to the small particle size and the porous structure which can be seen in the TEM characterization. On the basis of BJH model and the desorption data, the average pore radii dV(d) of SnO₂–SnO composite and SnO₂ nanoparticles were calculated to be 1.68 and 4.3 nm, respectively, as shown in Fig. 3 insets.

**3.2 Sensing performances of SnO₂–SnO hybrid and pure SnO₂ nanoparticles for NO₂ gas detection**

The sensing performances of the SnO₂–SnO hybrid and single
SnO₂ for NO₂ gas detection were studied and compared. First, operating temperature is one of important sensing properties of materials and low operating temperature is especially favorable for their practical application in real gas sensors. Fig. 4 shows the responses of the two materials towards 50 ppm NO₂ gas as a function of operating temperature. It can be seen that for both materials, the response intensity is dependent on the working temperature, i.e. increasing firstly with appearance of a peak, and then declining with the temperature further increasing. However, the response intensity and the optimum operating temperature are much different for the two materials. For the SnO₂–SnO hybrid, the sensing response gradually increases first with temperature increasing and reaches a maximum at 50 °C, and at even lower temperatures, ca. room temperature, the material still show weak response. Such result implies that after further optimization, sensors based on the SnO₂–SnO hybrids could have the sensing ability for NO₂ gas detection at room temperature. This is a big breakthrough for the semiconductor metal oxide-based gas sensor, since the NO₂ gas sensing can be achieved at room temperature without any aid of noble metal doping or large surface-area supports (e.g. graphene, carbon nanotubes).

However, the sensing response of the pure SnO₂ reaches the maximum at around 150 °C which is triple higher than that obtained from the SnO₂–SnO hybrid (50 °C). Moreover, the response intensity from pure SnO₂ is much lower than that of the SnO₂–SnO composite (about one fourth of the hybrid). From the XRD and TEM measurements, the particle size of pure SnO₂ is around 4 nm and the size of the SnO₂ nanoparticle on the surface of SnO is about 28 nm. According to the size effect, compared with larger nanoparticles, the smaller sized particles should have better sensing performance due to the larger surface area. However, the present study showed that the SnO₂–SnO hybrid with larger particle size exhibited much higher sensing performance. Therefore, the enhanced sensing performance of the SnO₂–SnO hybrid should be ascribed to the unique p-n heterojunction structure. Such excellent gas sensing properties with enhanced sensing response and much lowered operating temperature make the novel SnO₂–SnO hybrid structure a kind of promising gas sensor material for NO₂ gas detection.

The dynamic sensing response and recovery properties of the pure SnO₂ and SnO₂–SnO for NO₂ detection were investigated. Fig. 5A and B shows the sensing responses of SnO₂ and SnO₂–SnO.
Table 1 Summary of the gas sensing performances of SnO$_2$-based metal oxide nanomaterials with p-n heterostructure.

<table>
<thead>
<tr>
<th>Analyte</th>
<th>Composition</th>
<th>Synthesis route</th>
<th>Morphology</th>
<th>Operating Temp (°C)</th>
<th>Response</th>
<th>Concentration</th>
<th>LOD</th>
<th>Ref.</th>
</tr>
</thead>
<tbody>
<tr>
<td>NO$_2$</td>
<td>SnO$_2$SnO$_2$O</td>
<td>Hydrothermal method</td>
<td>SnO$_2$ particles loaded on WO$_3$ nanorods</td>
<td>N/A</td>
<td>52.7</td>
<td>50 ppm</td>
<td>N/A</td>
<td>36</td>
</tr>
<tr>
<td>C$_2$H$_5$OH</td>
<td>ZnO-SnO$_2$</td>
<td>Solution deposition</td>
<td>Core-shell</td>
<td>1.2 NO$_2$</td>
<td>10 ppm</td>
<td>10 ppm</td>
<td>56</td>
<td></td>
</tr>
<tr>
<td>CH$_3$COOH</td>
<td>ZnO-SnO$_2$</td>
<td>Hydrothermal method</td>
<td>CuO nanosheets</td>
<td>100 ppm</td>
<td>50 ppmTime (s)</td>
<td>N/A</td>
<td>38</td>
<td></td>
</tr>
<tr>
<td>CH$_3$COOH</td>
<td>ZnO-SnO$_2$</td>
<td>Thermal evaporation</td>
<td>SnO$_2$ nanorods</td>
<td>34</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>H$_2$S</td>
<td>CuO-SnO$_2$</td>
<td>Chemical vapour deposition</td>
<td>CuO particles</td>
<td>4.7</td>
<td>100 ppm</td>
<td>N/A</td>
<td>31</td>
<td></td>
</tr>
<tr>
<td>H$_2$S</td>
<td>CuO-SnO$_2$</td>
<td>Electrospraying</td>
<td>Fe$_2$O$_3$ nanowire</td>
<td>255</td>
<td></td>
<td></td>
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<tr>
<td>(CH$_3$)$_3$CHOH</td>
<td>SnO$_2$SnO$_2$O</td>
<td>Chemical vapour deposition</td>
<td>Composite nanowires</td>
<td>120</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>H$_2$</td>
<td>SnO$_2$SnO$_2$O</td>
<td>Hydrothermal method</td>
<td>Mixed phase</td>
<td>120</td>
<td></td>
<td></td>
<td></td>
<td></td>
</tr>
<tr>
<td>NO$_2$</td>
<td>SnO$_2$SnO$_2$O</td>
<td>Hydrothermal method</td>
<td>SnO$_2$ nanoparticles loaded on SnO$_2$ nanosheets</td>
<td>50</td>
<td></td>
<td></td>
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<td></td>
</tr>
</tbody>
</table>

Fig. 6 Detection selectivity of the SnO$_2$-SnO for 100 ppm NO$_2$, C$_2$H$_5$OH and CO at 50 °C. Inset shows the magnified response curves for C$_2$H$_5$OH and CO.

The much enhanced sensitivity of the SnO$_2$-SnO hybrid toward NO$_2$ gas at low temperature and suggest that the sensing mechanism of the SnO$_2$-SnO composites corresponds to the typical n-type semiconductor metal oxides.

Interestingly, we also found that the pure SnO$_2$ exhibits different sensing characteristics at low and high temperatures. As shown in Fig. 5C, at 75 °C the introduction of 50 ppm NO$_2$ gas leads to the increase of the resistance of pure SnO$_2$. However, at 175 °C the presence of NO$_2$ gas can result in the decrease of the resistance of SnO$_2$, which is totally opposite to the behavior at low temperature. In other words, the pure SnO$_2$ exhibits n-type characteristics at low temperature (75 °C) but shows overturned sensing behavior at 175°C with p-type sensing mechanism, which is different from those reported previously.

We will discuss this issue in the following part of gas sensing mechanism. The responses of the SnO$_2$-SnO$_2$ and pure SnO$_2$ as a function of NO$_2$ concentration are plotted in Fig. 5D. For the SnO$_2$-SnO$_2$ hybrid in the whole concentration range, a good linear fit was obtained with $R^2 = 0.943$. From the slope of the calibration line, the sensitivity of the SnO$_2$-SnO$_2$ hybrid for NO$_2$ detection was calculated to be 0.257 ppm$^{-1}$. Furthermore, the limit of detection (LOD) of the SnO$_2$-SnO$_2$ was estimated to be 0.1 ppm based on the LOD = $3 \alpha_0/ \alpha$ (where $\alpha$ is the slope of linear part of the calibration curve and $\alpha_0$ is the standard deviation of noise in the response curve in air). In sharp contrast, a linear fit with $R^2 = 0.555$ was obtained from the pure SnO$_2$ nanoparticles. Compared with the high sensitivity and low LOD of the SnO$_2$-SnO$_2$, the pure SnO$_2$ material is not sensitive to the concentration variation of NO$_2$ gas (green fitting line) with the sensitivity and theoretical LOD of 0.007 ppm$^{-1}$ and 0.6 ppm, respectively. Meanwhile, it can be seen that the SnO$_2$ sensor reaches sensing saturation at very low concentration and thus the concentration change of the target gas can be hardly distinguished. These results strongly indicate that the SnO$_2$-SnO$_2$ hybrid have enhanced sensing performance for NO$_2$ gas compared to pure SnO$_2$ nanomaterials. Table 1 summarizes the sensing performances of SnO$_2$-based hybrid metal oxide nanomaterials with p-n heterostructure for detection of different gases. Clearly, in this study, the optimum temperature, limit of detection and the response intensity to 100 ppm target gas almost exceed those in the previous reports. The sensing selectivity of the SnO$_2$-SnO$_2$ hybrid for NO$_2$ gas was also examined. As shown in Fig. 6, with SnO$_2$-SnO$_2$ exposed to 100 ppm NO$_2$, C$_2$H$_5$OH and CO at 50 °C, the response intensity to NO$_2$ is significantly larger than those to C$_2$H$_5$OH and CO gases, indicating the high selectivity of the p-n heterojunction nanostructure for NO$_2$ detection.
performance of the SnO₂-SnO hybrid makes it promising sensing material in application of real NO₂ gas sensors.

![Graph showing variation of resistance with time for SnO₂-SnO hybrid](image)

**Fig. 7** Variation of resistance ($R_t$) measured in air with time for SnO₂-SnO (top) and SnO₂ (bottom) having varied temperature from approximately 20 to 200 °C (target temp.)

### 3.3 Gas sensing mechanism of the SnO₂-SnO composites with p-n heterojunction

From our studies, the SnO₂-SnO hybrid with p-n junction exhibited improved sensing properties compared to the pure SnO₂ material. Here, we propose a sensing mechanism of the SnO₂-SnO p-n heterojunction nanostructure. The semiconductive properties of the two materials were firstly studied. The variation of resistances of hybrid SnO₂-SnO and pure SnO₂ materials in air as a function of time in the temperature range from ~20 to 200 °C. We can see that these two sensing materials show different variation tendency although they belong to the same type of semiconductor metal oxides (n-type). SnO₂ is a well-known n-type semiconductor (majority carrier is electron). Thus, with temperature rising, the oxygen in air can be adsorbed on the surface of SnO₂ to create chemisorbed oxygen species ($O_2^-$, $O^-$, $O^2-$) and consume the inner electrons. Such process could produce surface polarization energy level and result in the increase of bulk resistance. With oxygen species concentration reach saturation, bulk resistance entry a relative stable state (bottom of Fig. 7). As shown in top of Fig. 7, the resistance variation of SnO₂-SnO is a little more complicated than the pure SnO₂ sample. Compared with n-type SnO₂, SnO belongs to p-type semiconductor (majority carrier is hole). With temperature increasing, the resistance of the hybrid rises firstly and then declines to a stable state, which can be explained as follows. In the composite, oxygen is firstly adsorbed on the surface of the SnO₂ material and the oxygen ionization process can consume large mount of free electrons and thus holes were left in the composites, leading to the increase of resistance just like the pure SnO₂. With temperature further increasing, SnO nanocrystals become the active and main component for chemosorption of oxygen, resulting in the further increase of holes concentration in the conduction band of the composite. The increase of holes concentration can enhance the speed of electron penetration on both sides of p-n heterojunction, resulting in the declining tendency of the resistance of the hybrids. Similar to the pure SnO₂ sample, the resistance reaches a relative stable value in the end.

![Diagram showing general schematic of the heterostructure of n-SnO₂ nanoparticles on the surface of p-SnO nanosheets with a p-n junction](image)

**Fig. 8** (A) General schematic of the heterostructure of n-SnO₂ nanoparticles on the surface of p-SnO nanosheets with a p-n junction. (B) UV-vis spectra of SnO₂-SnO and pure SnO₂ materials. Inset shows the plot of $(\alpha h\nu)$ versus $(h\nu)$ from the pure SnO₂.

The n-type SnO₂ and p-type SnO can form a heterojunction structure at the interface, which is considered to be the primary reason for the enhanced sensing response and low operation temperature of the hybrid material. As shown in Fig. 8A, theoretically the forbidden band width between $E_c$ (conduction band) and $E_v$ (valence band) is 3.6 eV in SnO₂ semiconductor and is about 2.9 eV in SnO. The p-n heterojunction leads to the formation of depletion region. It can be seen that the bending of forbidden bands occurs at the interface zone to make the $E_f$ (Fermi level) equilibrium between SnO₂/SnO band gaps. In general, the narrower the width of forbidden band, the lower energy is required for the transition of electrons near the bottom of the conduction band. The UV-vis spectra of the SnO₂-SnO and pure SnO₂ materials are shown in Fig. 8B, from which the band gaps of these two samples can be evaluated. From the calculations, even though the actual forbidden band widths of these two samples are larger that than of bulk SnO₂ (3.6 eV) due to the quantum confinement effect, the band width of the SnO₂-SnO hybrid is much lower (3.79 eV) than that of pure SnO₂ (4.6 eV). The change of the band gap can well explain the reason that the operation temperature of the SnO₂-SnO composites is much lower than that of the pure n-SnO₂. Meanwhile, as soon as the concentration of the oxygen anions (mainly $O^2-$) gets a saturation value, the height of potential barrier and the width of depletion region will not change. The width of depletion zone will directly decide the response of a sensor at low temperature ranges. When the sensors are exposed to NO₂ gas (oxidizing gas),
NO₂ molecules are absorbed on the surface of both SnO₂ and uncovered SnO. Similar to the pure SnO₂ sensor, the absorbed NO₂ can capture the electrons from the conduction bands of the semiconductors, resulting in the increase of the resistance of SnO₂-SnO composites which can be seen in Fig. 5B. After trapping electrons from conduction band and anion oxygen, NO₂ gas molecules became NO₃⁻. At the same time, chemisorbed oxygen species were released to air once more. When the surface of samples are almost fully covered by NO₃⁻, the mobility of free electrons on the surface are largely reduced and make the resistance of composites increase to a saturation value. Meanwhile, the reduced mobility of free electrons and the increased holes concentration could lead to the increase of thickness of depletion region, which may be another reason for the increase of sensor resistance.⁴⁷

When NO₂ was adsorbed on pure SnO₂, owing to the strong oxidability of NO₂, the electrons captured by NO₂ can be hardly exchanged with fresh oxygen, which may be responsible for the poor recovery of pure SnO₂. On the other hand, when the pure SnO₂ sensor was exposed to NO₂ gas at high temperature, because of the hard releasing of captured electron, NO₃⁻ can be formed on the surface of composites, and meanwhile, abundant holes are left in the conduction band and become the major carriers. Therefore, the SnO₂ showed p-type semiconductor properties and the resistance showed a decrease in the process. Such interesting phenomenon (called percolation behavior) has also been reported by Neri et al.⁵¹,⁵⁵

4. Conclusion

The gas sensing properties of SnO₂-SnO composite material with p-n heterojunction structure have been investigated for detection of NO₂ gas. The results showed that the sensing performance of the SnO₂-SnO hybrid is much higher than that of pure SnO₂ nanoparticles. The optimum temperature of SnO₂-SnO sensor is as low as 50 °C, at which the sensor showed excellent linearity between sensing response and the concentration of NO₂ gas with a wide concentration range (15 to 110 ppm), low LOD (ca. 0.1 ppm) and good selectivity. Even though the pure SnO₂ nanoparticles possess small crystalline grain size and large specific surface area, the sensing performance of pure SnO₂ for NO₂ gas detection is still lower than that of the SnO₂-SnO hybrids. In the proposed sensing mechanism, the p-n heterojunction structure formed at the interface of SnO₂-SnO may account for the improved sensing performance, especially the much lowered operation temperature. The present study shows that in addition to optimizing crystal size and improving specific surface area, fabricating semiconductor materials with p-n heterojunction structure is also a very efficient way to design gas sensor with high sensing performance.

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Notes and references

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